

# BLC10G18XS-551AVT

Power LDMOS transistor

Rev. 1 — 5 November 2018

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

550 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1805 MHz to 1880 MHz.

**Table 1. Typical performance**

Typical RF performance at  $T_{case} = 25\text{ }^{\circ}\text{C}$  in an asymmetrical Doherty demo circuit.  $V_{DS} = 32\text{ V}$ ;  $I_{DQ} = 750\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.18\text{ V}$ , unless otherwise specified.

Test signal	f	$V_{DS}$	$P_{L(AV)}$	$G_p$	$\eta_D$	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1805 to 1880	32	50.6	17.0	51	-32.5 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- For RoHS compliance see the product details on the Ampleon website

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1880 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain2 (peak)		<p>aaa-014884</p>
2	drain1 (main)		
3	gate1 (main)		
4	gate2 (peak)		
5	source <a href="#">[1]</a>		
6	video decoupling (peak)		
7	video decoupling (main)		

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLC10G18XS-551AVT	-	air cavity plastic earless flanged package; 6 leads	SOT1258-4

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-6	+9	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-6	+9	V
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature		<a href="#">[1]</a>	225	°C
$T_{case}$	case temperature	operating	<a href="#">[1]</a>	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$V_{DS} = 32\text{ V}; I_{Dq} = 950\text{ mA (main)};$ $V_{GS(amp)peak} = 1.03\text{ V}; T_{case} = 80\text{ °C}$		
		$P_L = 115\text{ W}$	0.21	k/W
		$P_L = 145\text{ W}$	0.19	k/W

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Main device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1.8\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 180\text{ mA}$	1.6	2.0	2.4	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 32\text{ V}; I_D = 800\text{ mA}$	-	2.2	-	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 2.37\text{ V}; V_{DS} = 10\text{ V}$	-	34	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 9.0\text{ A}$	-	20.5	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 2.37\text{ V}; I_D = 6.3\text{ A}$	-	72	108	$\text{m}\Omega$
<b>Peak device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 3.8\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 380\text{ mA}$	1.6	2.0	2.4	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 32\text{ V}; I_D = 1900\text{ mA}$	-	2.2	-	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 2.37\text{ V}; V_{DS} = 10\text{ V}$	-	57	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 19.0\text{ A}$	-	39.0	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 2.37\text{ V}; I_D = 13.3\text{ A}$	-	37	62	$\text{m}\Omega$

**Table 7. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH;  $f_1 = 1807.5\text{ MHz}; f_2 = 1877.5\text{ MHz}$ ; RF performance at  $V_{DS} = 32\text{ V}; I_{Dq} = 800\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.0\text{ V}; T_{case} = 25\text{ }^\circ\text{C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 1805 MHz to 1880 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$P_{L(AV)} = 115\text{ W}$	15.1	16.1	-	dB
$RL_{in}$	input return loss	$P_{L(AV)} = 115\text{ W}$	-	-11	-7	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 115\text{ W}$	46	50	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 115\text{ W}$	-	-32	-27	dBc

**Table 8. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH;  $f = 1877.5\text{ MHz}$ ; RF performance at  $V_{DS} = 32\text{ V}; I_{Dq} = 800\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.0\text{ V}; T_{case} = 25\text{ }^\circ\text{C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 1880 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$PAR_O$	output peak-to-average ratio	$P_{L(AV)} = 148\text{ W}$	6.3	6.8	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)} = 148\text{ W}$	620	705	-	W

## 7. Test information

### 7.1 Ruggedness in Doherty operation

The BLC10G18XS-551AVT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 800\text{ mA}$ ;  $V_{GS(amp)peak} = 1.15\text{ V}$ ;  $f = 1805\text{ MHz}$ ;  $P_L = 235\text{ W}$  (5 dB OBO); 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 7.2 Impedance information

**Table 9. Typical impedance of main device**

Measured load-pull data of main device;  $I_{Dq} = 900\text{ mA}$  (main);  $V_{DS} = 32\text{ V}$ ; pulsed CW ( $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\text{ }\%$ ).

f (MHz)	Z <sub>S</sub> [1] ( $\Omega$ )	Z <sub>L</sub> [1] ( $\Omega$ )	P <sub>L</sub> [2] (W)	$\eta_D$ [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
1810	2.2 – j6.0	1.6 – j3.5	309	59.7	16.3
1845	2.9 – j6.6	1.7 – j3.2	311	60.8	16.6
1880	3.9 – j7.1	1.6 – j3.2	307	60.3	16.7
<b>Maximum drain efficiency load</b>					
1810	2.5 – j6.4	2.5 + j1.9	204	71.8	18.9
1845	3.3 – j6.9	2.0 + j1.4	223	71.0	18.7
1880	4.5 – j7.4	1.8 + j1.7	221	70.3	18.9

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.

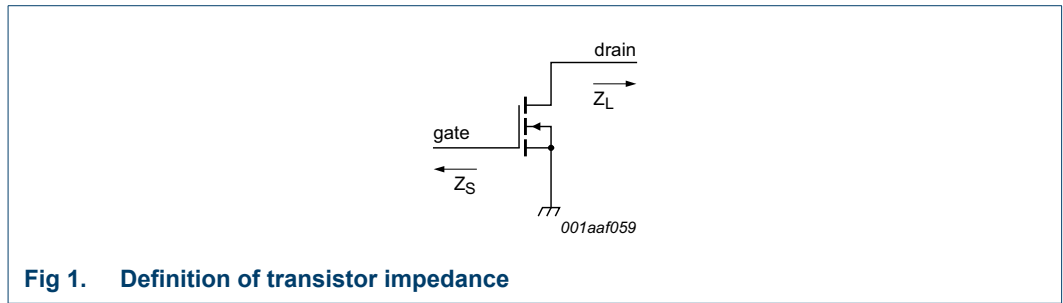
**Table 10. Typical impedance of peak device**

Measured load-pull data of peak device;  $I_{Dq} = 1900\text{ mA}$  (peak);  $V_{DS} = 32\text{ V}$ ; pulsed CW ( $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\text{ }\%$ ).

f (MHz)	Z <sub>S</sub> [1] ( $\Omega$ )	Z <sub>L</sub> [1] ( $\Omega$ )	P <sub>L</sub> [2] (W)	$\eta_D$ [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
1810	1.4 – j6.1	1.7 – j2.4	574	61.4	15.7
1845	1.9 – j6.7	1.6 – j2.6	583	58.7	15.6
1880	2.4 – j7.3	1.6 – j2.5	581	60.4	16.0
<b>Maximum drain efficiency load</b>					
1810	1.4 – j6.1	2.3 + j1.4	464	67.9	17.1
1845	1.9 – j6.7	1.9 + j1.4	453	65.9	17.3
1880	2.4 – j7.3	1.7 + j1.6	489	66.2	17.2

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.



7.3 Test circuit

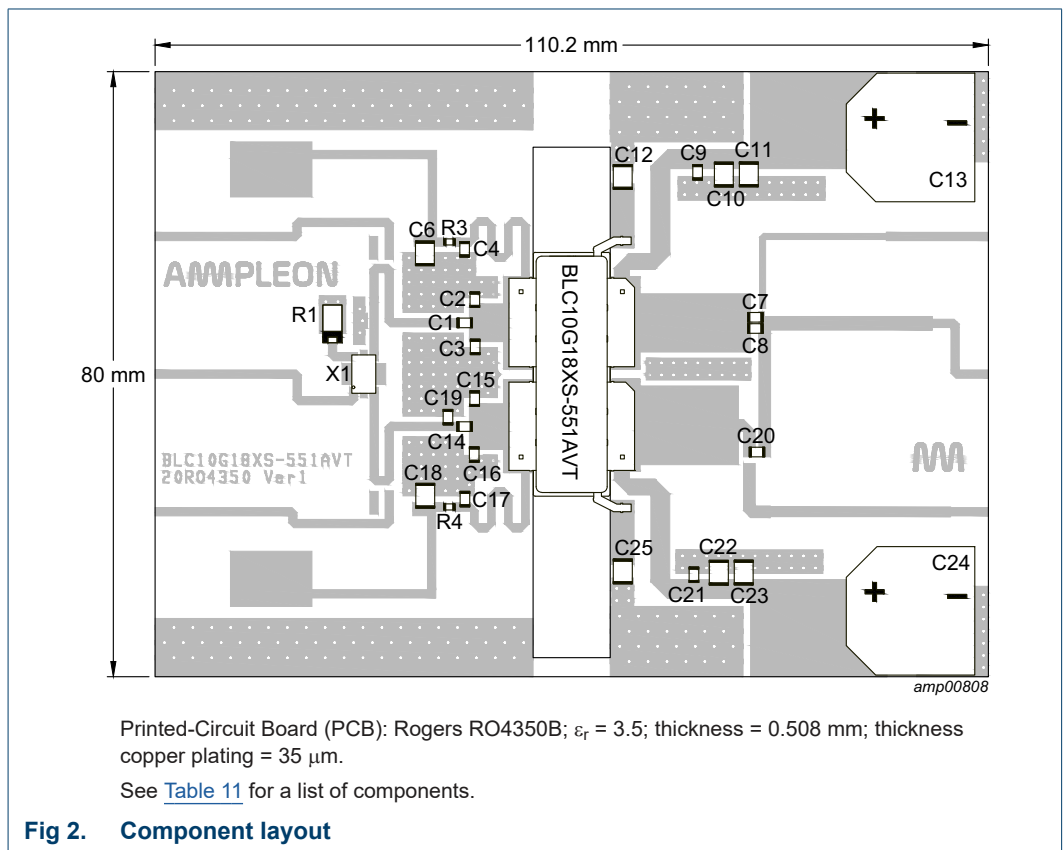


Table 11. List of components

See [Figure 2](#) for component layout.

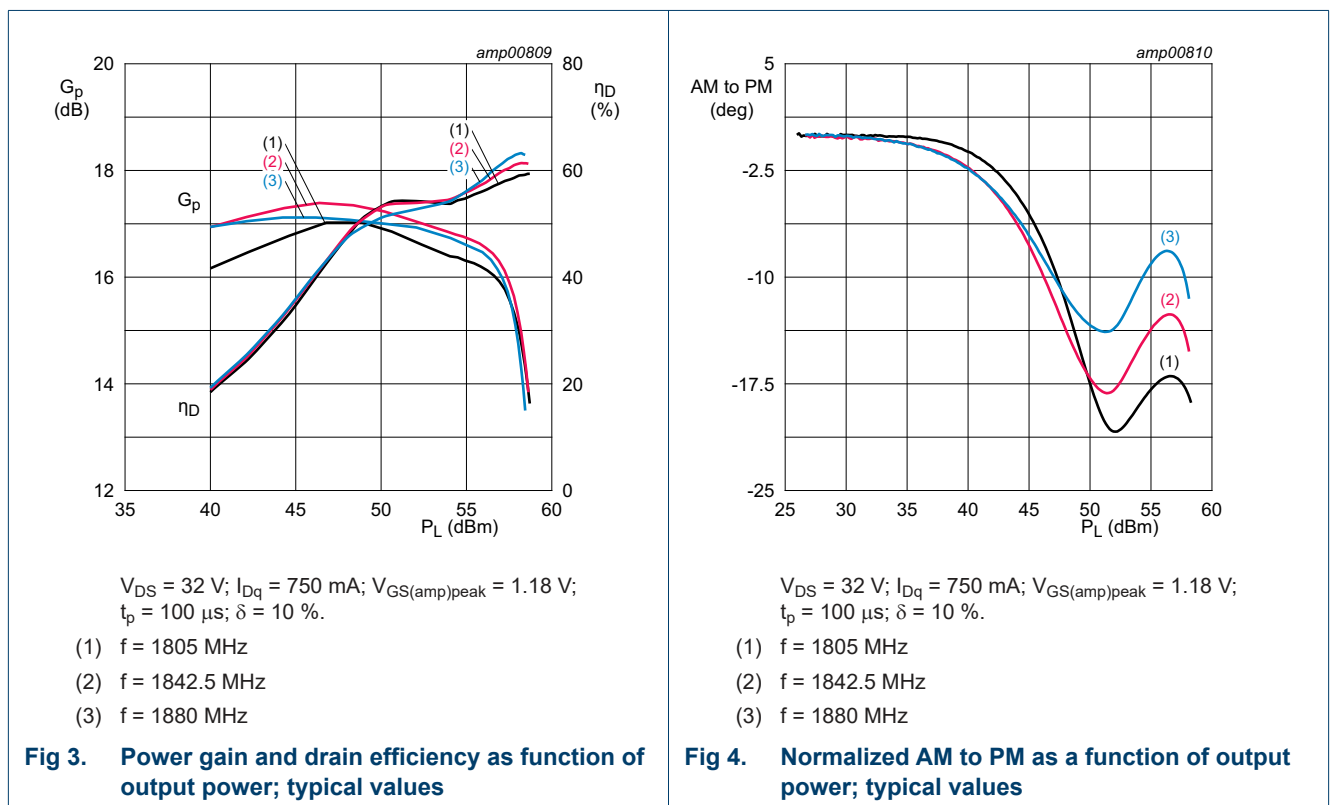
Component	Description	Value	Remarks
C1, C4, C7, C8, C9, C14, C17, C20, C21	multilayer ceramic chip capacitor	10 pF	Murata: GQM21 Hi-Q 250V series, SMD 0805
C2	multilayer ceramic chip capacitor	1.2 pF	Murata: GQM21 Hi-Q 250V series, SMD 0805
C3	multilayer ceramic chip capacitor	1.5 pF	Murata: GQM21 Hi-Q 250V series, SMD 0805
C6, C10, C11, C12, C18, C22, C23, C25	multilayer ceramic chip capacitor	4.7 $\mu\text{F}$ , 100 V	Murata Hi-Q GRM42-256X7S475K100H530, SMD1210
C13, C24	electrolytic capacitor	470 $\mu\text{F}$ , 100 V	Vishay: MAL225099913E3
C15, C16	multilayer ceramic chip capacitor	2.0 pF	Murata: GQM21 Hi-Q 250V series, SMD 0805

**Table 11. List of components ...continued**  
See [Figure 2](#) for component layout.

Component	Description	Value	Remarks
C19	multilayer ceramic chip capacitor	0.5 pF	Murata: GQM21 Hi-Q 250V series, SMD 0805
R1	resistor	50 Ω, 125 W	Anaren: C16A50Z4
R3, R4	resistor	4.7 Ω, 1 %	SMD 0603
X1	hybrid coupler	2 dB, 90°	Anaren: X3C20F1-02S

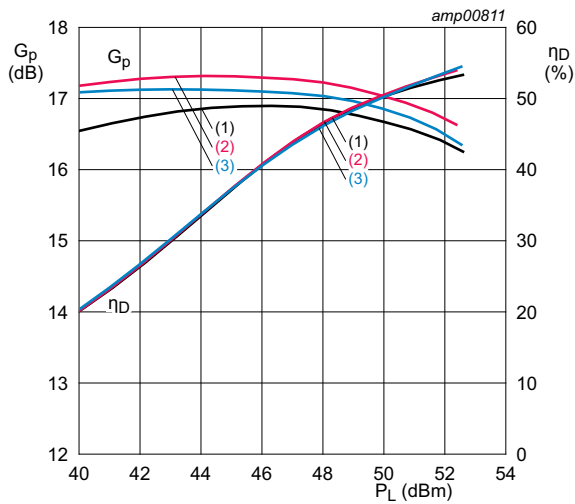
## 7.4 Graphical data

### 7.4.1 Pulsed CW



7.4.2 1-Carrier W-CDMA

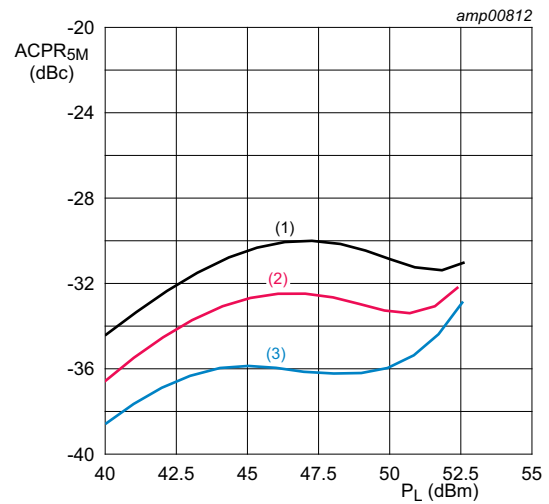
Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01 % probability on CCDF.



$V_{DS} = 32\text{ V}; I_{Dq} = 750\text{ mA}; V_{GS(amp)peak} = 1.18\text{ V}.$

- (1)  $f = 1805\text{ MHz}$
- (2)  $f = 1842.5\text{ MHz}$
- (3)  $f = 1880\text{ MHz}$

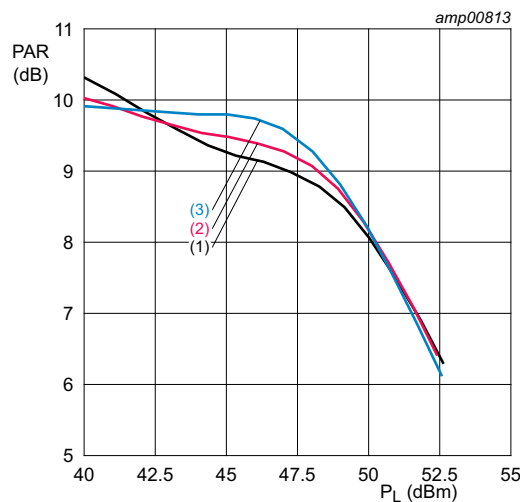
Fig 5. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 32\text{ V}; I_{Dq} = 750\text{ mA}; V_{GS(amp)peak} = 1.18\text{ V}.$

- (1)  $f = 1805\text{ MHz}$
- (2)  $f = 1842.5\text{ MHz}$
- (3)  $f = 1880\text{ MHz}$

Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



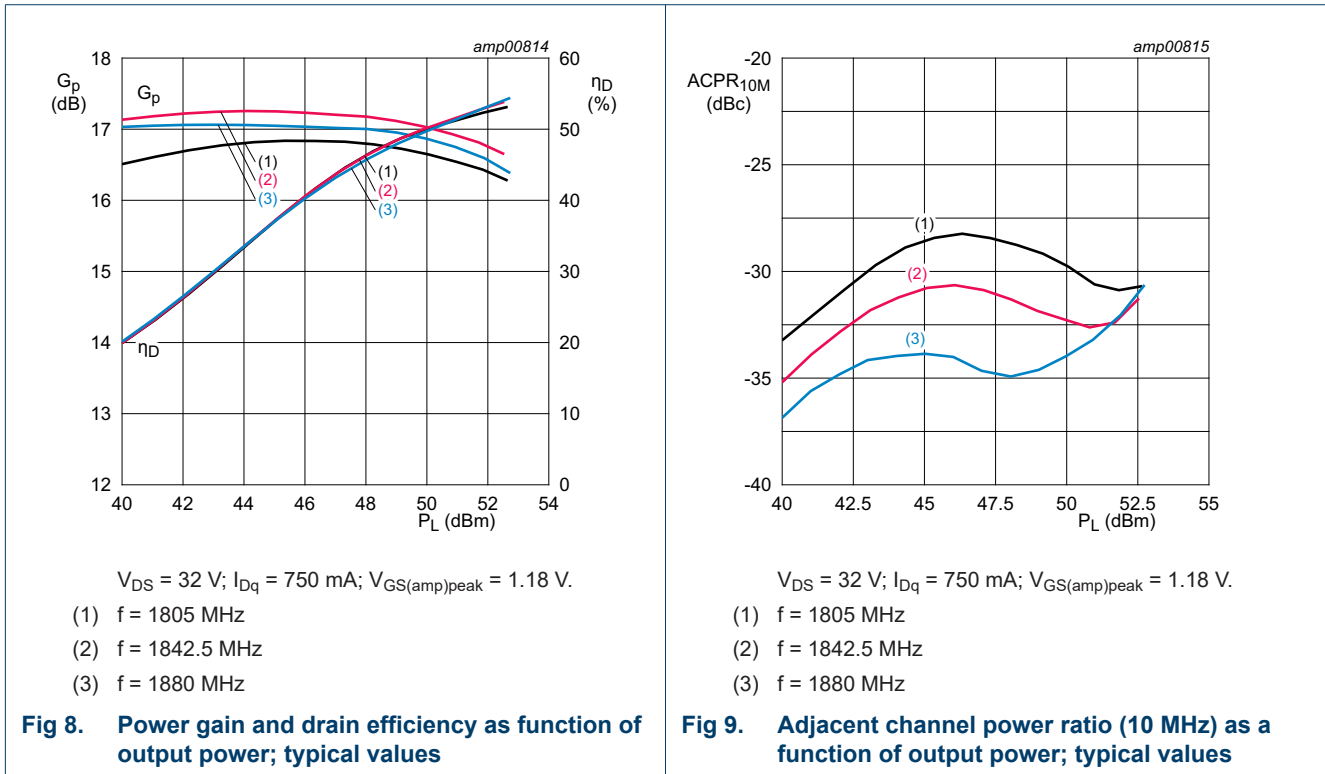
$V_{DS} = 32\text{ V}; I_{Dq} = 750\text{ mA}; V_{GS(amp)peak} = 1.18\text{ V}.$

- (1)  $f = 1805\text{ MHz}$
- (2)  $f = 1842.5\text{ MHz}$
- (3)  $f = 1880\text{ MHz}$

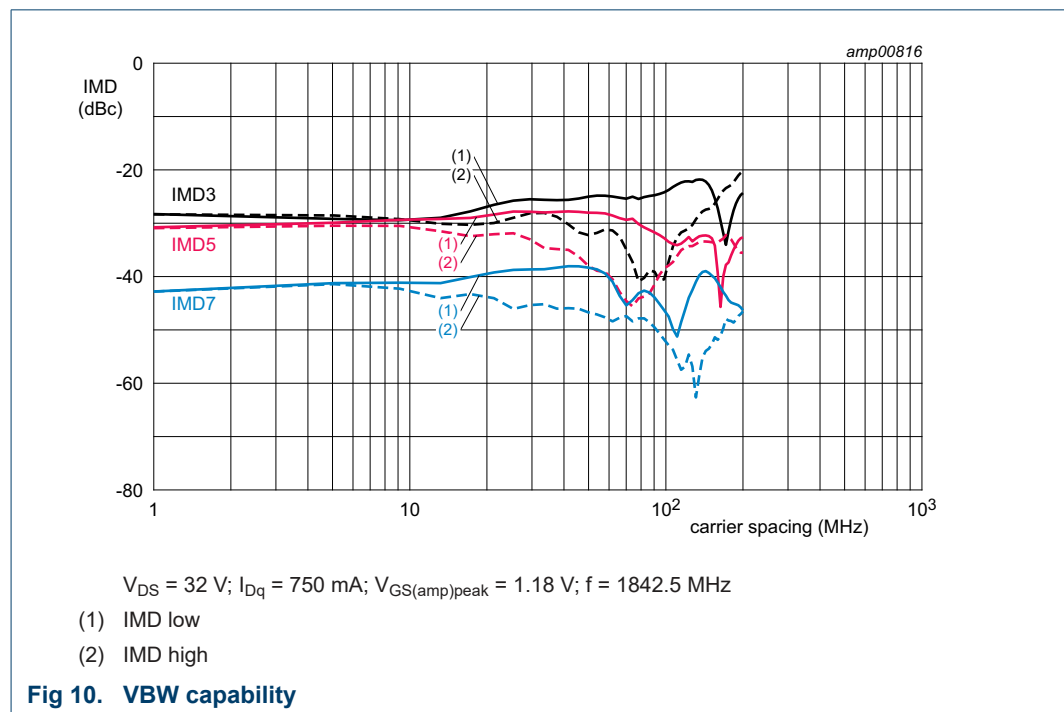
Fig 7. Peak-to-average power ratio as a function of output power; typical values

7.4.3 1-Carrier LTE

Test signal: 1-carrier LTE 10 MHz; PAR = 6.8 dB at 0.01 % probability on CCDF.

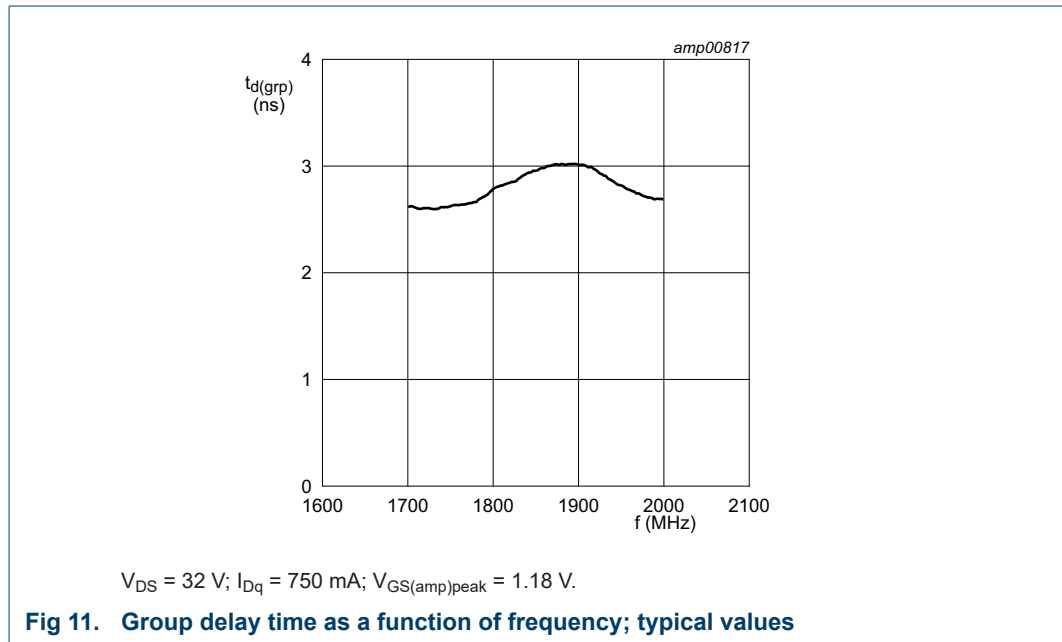


7.4.4 2-Tone VBW





7.4.5 Group delay



### 8. Package outline

Air cavity plastic earless flanged package; 6 leads

SOT1258-4

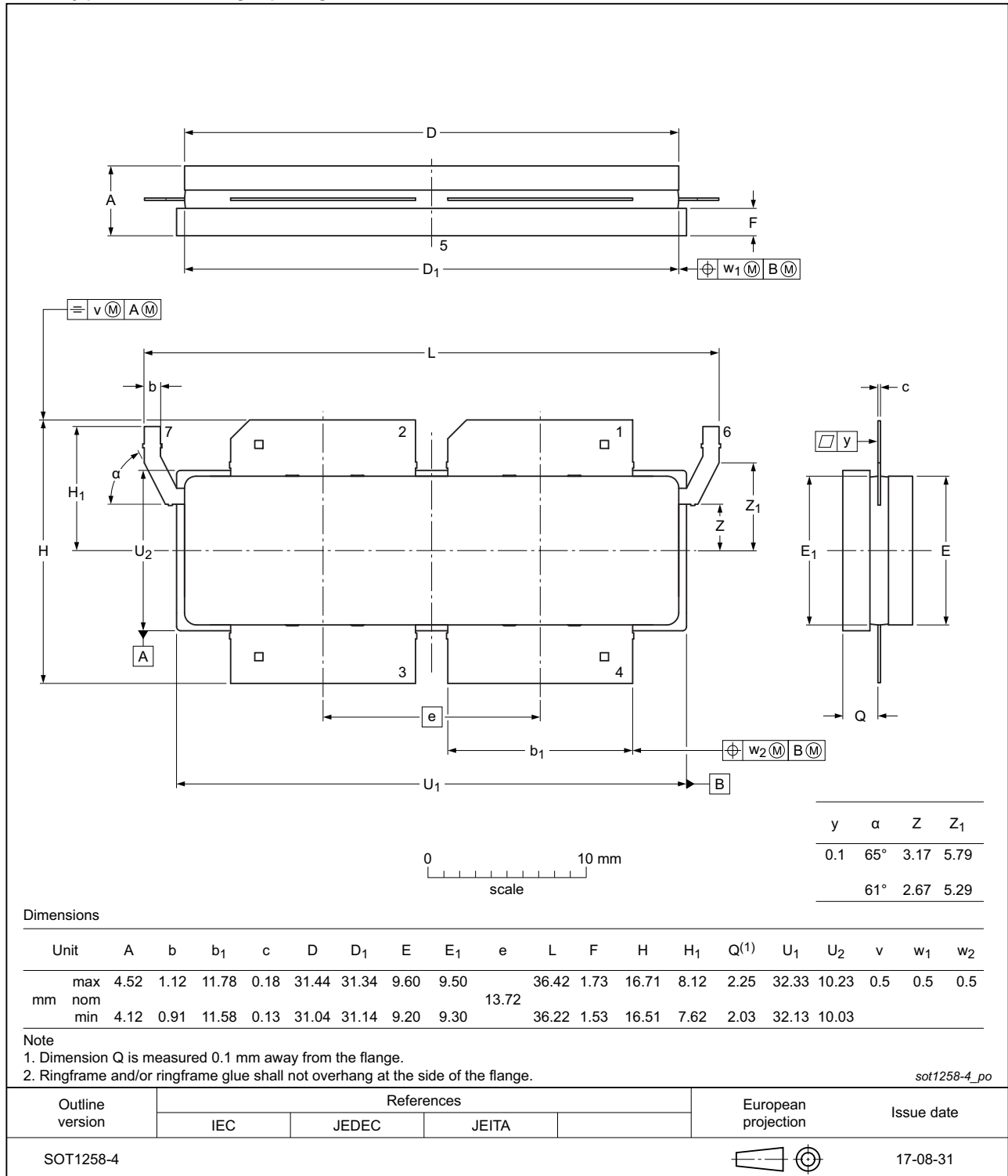


Fig 12. Package outline SOT1258-4

## 9. Handling information

**CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

**Table 12. ESD sensitivity**

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 <a href="#">[1]</a>
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 <a href="#">[2]</a>

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

## 10. Abbreviations

**Table 13. Abbreviations**

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back Off
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

## 11. Revision history

**Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC10G18XS-551AVT v.1	20181105	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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